

## **4-way Single L-Band Active** Typical applications: Satellite operators, VSAT, teleports & broadcasters Combiner High resilience RF • distribution & optimum satellite signal quality with dual redundant amplifiers and internal/external 10 MHz reference source Local Monitoring via 850 - 2150 MHz **Compact** 1 x 4-way front panel status LEDs operating frequency combiner housed in a 1U for amplifier & PSU range high chassis etl L Band Combiner AMP STATUS www.etlsystems.com 0 PSU1 FAIL PSU2 FAIL INT 10MHz 10MHz OP 10MHz IP IN3 CE 0 GD00972 22469-F7N5 www.etl **10 MHz Reference Dry contact alarm Resilience** from either via an internal dual redundant port for power supply source, switchable on/off power supplies status or via an external source



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## Model Number: C0401S1ULA-22469-XXXX

## Technical specifications and operating parameters

RF Parameters							
Capacity		4 - way Combiner					
Frequency		850 to 2150 MHz (L-band)					
Connector & impedances		50Ω BNC	50Ω SMA	50Ω N-Type	75Ω BNC	75Ω F-Type	
Nominal Gain		1±2 dB Mean across band					
Gain flatness	Full band	±1.0 dB	±1.0 dB	±1.0 dB	±1.2 dB	±1.4 dB	
	Any 36MHz	±0.5 dB	±0.5 dB	±0.5 dB	±0.6 dB	±0.7 dB	
Input Return Loss	Typical	16 dB	16 dB	16 dB	14 dB	14 dB	
	Minimum	12 dB	12 dB	12 dB	8 dB	8 dB	
Output Return Loss	Typical	18 dB	18 dB	18 dB	16 dB	16 dB	
	Minimum	11 dB	12 dB	12 dB	8 dB	8 dB	
Group Delay	Full band	2 ns maximum		ו	Pk to pk a	cross band	
Variation	Any 36 MHz	1 ns maximum		n	Pk to pk across band		
Amplification		Dual redundant amplifier, cold standby, 1:1 redundancy with					
	Typical	28 dB			Minimum between 2		
Isolation	Minimum		21 dB		Minimum between 2		
Noise Figure		21 dB					
Output 1dB GCP	)	8 dBm					
Input RF Power			16 dBm		Absolute m	naximum	
			10 MHz				
Internal Referer	nce		10 MHz 10 MHz Sin	e Wave	Ovenise Oscil	d Crystal lator	
Internal Referer	nce Level		10 MHz 10 MHz Sin	e Wave + 10 dBr	Ovenise Oscil m ± 2 dB	d Crystal lator	
Internal Referen 10 MHz Output Frequency Stabi	ice Level lity Over Tempe	erature	<b>10 MHz</b> 10 MHz Sin ± 1 x 1	e Wave + 10 dBr 0 <sup>-8</sup>	Ovenise Oscil m ± 2 dB 0 to +	d Crystal lator - 55°C	
Internal Referen 10 MHz Output Frequency Stabil Reference Source	ice Level lity Over Tempe æ Ageing	erature	<b>10 MHz</b> 10 MHz Sin ± 1 x 1	e Wave + 10 dBr 0-8 ± 5 x 10 ± 5 x 1	Ovenise Oscil m ± 2 dB 0 to + 0 <sup>-8</sup> /year 0 <sup>-10</sup> /day	d Crystal lator - 55°C	
Internal Referen 10 MHz Output Frequency Stabil Reference Source	ice Level lity Over Tempe æ Ageing @ 1 Hz	erature	10 MHz 10 MHz Sin ±1 x 1	e Wave + 10 dBr 0-8 ± 5 x 11 ± 5 x 1 - 85 c	Ovenise Oscil m ± 2 dB 0 to + 0 <sup>-8</sup> /year 0 <sup>-10</sup> /day dBc/Hz	d Crystal lator - 55°C	
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Internal Referen 10 MHz Output Frequency Stabil Reference Source Phase Noise Warm up Time 10 MHz reference	nce Level lity Over Tempe te Ageing @ 1 Hz @ 10 MH @ 1000 M @ 1000 M @ 10,000	erature	10 MHz Sin 10 MHz Sin ± 1 x 1 ( - - - - - - - - - - - - -	e Wave + 10 dBr 0-8 ± 5 x 10 ± 5 x 11 < -85 c < -115 < -140 < -150 < -155 utes ar panel ternal/ e 10 MHz injected nmon L- ort.	Ovenise Oscil m ± 2 dB 0 to + 0* /year 0-10/day dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz it composition for the second for the s	d Crystal lator - 55°C - 55°C 	

Environmental		
Operating temperature	0 to 50°C	
Location	Indoor use only	
Storage temperature	-20°C to +75°C	
Humidity	85% non-condensing. Relative Humidity.	
Altitude	10,000 feet AMSL (above mean sea level)	

Power				
PSU Power	85-264Vac 50/60Hz	Fused 2A		
BUC Power	None			
PSU Redundancy	Dual redundant with dual IEC inlets.	Diode OR. Not hot-swap		
AC Consumption	<10 W	At steady state		

System Control & Alarms		
Alarms	Dry contact, change-over via 9-way D-type. Available alarms are: PSU supply.	
Display	Tri coloured LED's to indicate amplifier status, LEDs for PSU status and power on.	

Physical		
Dimensions	1U high x 350mm deep x 19" wide	
Weight	3.65 kg	
Colour	RAL9003- White (Semi-Matte)	

## **Preliminary Specifications**

Note 1: The specification is subject to regular reviews and will be updated from time to time as part of our continuing product development and improved spec accuracy.

Note 2: Operation beyond the quoted limits stated above may cause instantaneous and permanent damage.



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